

RoHS

COMPLIANT HALOGEN

FREE



Vishay General Semiconductor

# **High Current Density Surface Mount Schottky Barrier Rectifiers**



DO-220AA (SMP)

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2.0 A				
V <sub>RRM</sub>	20 V, 30 V, 40 V				
I <sub>FSM</sub>	50 A				
E <sub>AS</sub>	11.25 mJ				
V <sub>F</sub>	0.50 V				
T <sub>J</sub> max.	150 °C				

#### **TYPICAL APPLICATIONS**

For use in low voltage high frequency inverters, freewheelling, dc-to-dc converters, and polarity protection applications.

#### **FEATURES**

- · Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency
- · Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 265 °C max. 10 s, per JESD 22-A111
- · Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

#### **MECHANICAL DATA**

Case: DO-220AA (SMP)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS2P2	SS2P3	SS2P4	UNIT
Device marking code		22	23	24	
Maximum repetive peak reverse voltage	V <sub>RRM</sub>	20	30	40	V
Maximum average forward rectified current (Fig. 1)	I <sub>F(AV)</sub>	2.0			Α
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	50			Α
Non-repetitive avalanche energy at $I_{AS} = 1.5 \text{ A}$ , $L = 10 \text{ mH}$ , $T_J = 25 ^{\circ}\text{C}$	E <sub>AS</sub>	11.25			mJ
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000		V/µs	
Operating junction and storage temperature range	T <sub>J,</sub> T <sub>STG</sub>	- 55 to + 150			°C

### SS2P2, SS2P3 & SS2P4

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage (1)	I <sub>F</sub> = 2 A I <sub>F</sub> = 2 A	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	V <sub>F</sub>	0.50 0.43	0.55 0.50	V	
Maximum reverse current at rated V <sub>R</sub> <sup>(2)</sup>		T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	- 8	150 15	μA mA	
Typical junction capacitance	4.0 V, 1 MHz		CJ	1	10	pF	

#### Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS2P2	SS2P3	SS2P4	UNIT
40	$R_{\theta JA}$	115			
Typical thermal resistance (1)	$R_{ hetaJL}$	15			°C/W
	$R_{ hetaJC}$		20		

#### Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas.  $R_{\theta JL}$  is measured at the terminal of cathode band.  $R_{\theta JC}$  is measured at the top centre of the body

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
SS2P4-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel			
SS2P4-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel			
SS2P4HM3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel			
SS2P4HM3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel			

#### Note:

(1) AEC-Q101 qualified

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

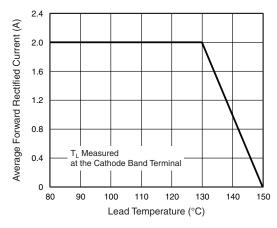


Figure 1. Forward Current Derating Curve

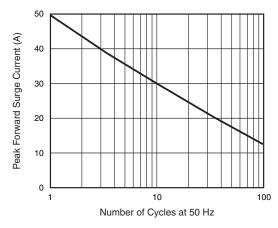


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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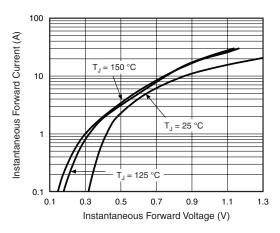


Figure 3. Typical Instantaneous Forward Characteristics

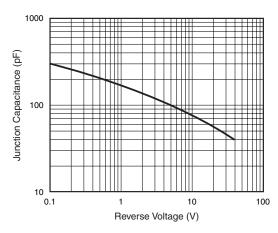


Figure 5. Typical Junction Capacitance

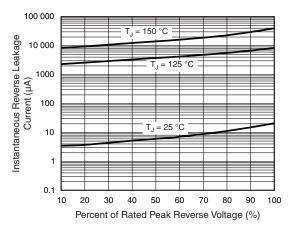


Figure 4. Typical Reverse Leakage Characteristics

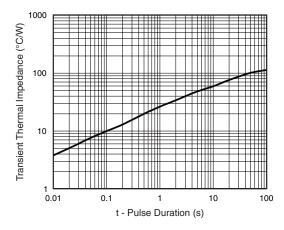
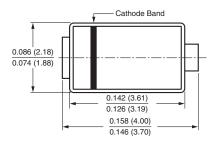
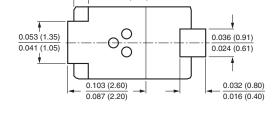


Figure 6. Typical Transient Thermal impedance

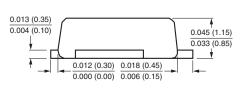
### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

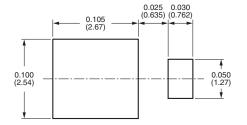
#### DO-220AA (SMP)





0.012 (0.30) REF.







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